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# Understanding Brewer Science's Bottom Anti-Reflective Coatings



**Brewer Science Inc., Rolla MO, USA**

Effective Date: 0X/0X/02 DCIF: MKT00XX Doc. Control#: F.6.6.010X.A

# Overview

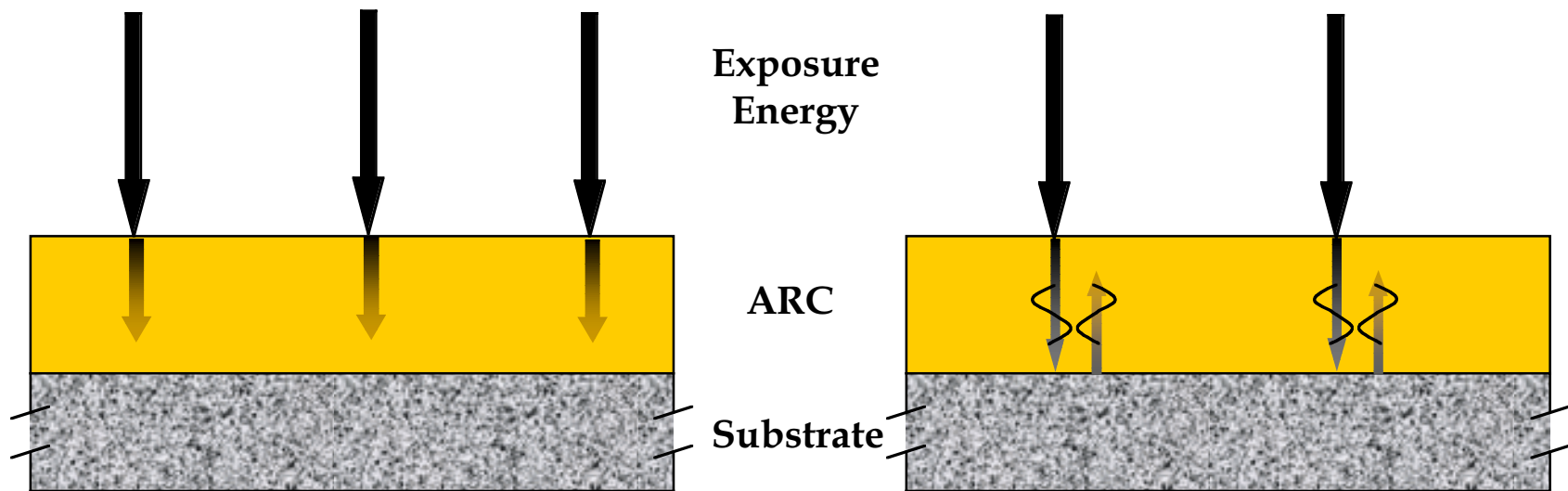
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- Anti-reflective coating introduction
- Types of anti-reflective coating
- Advantages to anti-reflective coatings
- Advantages to bottom anti-reflective coatings
- Guide to products and compatibility



# Anti-Reflective Coating Introduction

- Anti-reflective coatings (ARC) can do several things
  - Absorb light entering the material by light absorbing compounds in material.
  - If ARC is the correct thickness can cause destructive interference of reflected light.



# Types of Anti-reflective Coatings

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- Organic
  - Applied like a photoresist
  - Top anti-reflective coating (TARC)
    - Applied after the photoresist
    - Absorbs light to give little reflection at substrate/resist surface
  - Bottom anti-reflective coating (BARC)
    - Applied before the photoresist
    - Absorbs light and uses destructive interference to give little reflection at the resist/ARC interface
- Inorganic
  - Deposited on substrate in special deposition chamber



# Organic and Inorganic ARC

Property	Organic ARC	Inorganic ARC
Reflectivity and swing ratio reduction - 1 <sup>st</sup> minimum	++	+++
Reflectivity and swing ratio reduction - 2 <sup>nd</sup> and higher minima	+++	0
Etch rate	0 or +	+++
Coating conformity	0	++
Thickness tolerance	+	0
Plasma damage	+++	--
Refr. index reproducibility	+++	0
Throughput	++	+
Cost of Ownership	+	0
Stack issues	+++	-
Planarization capability	++	--
Rework capability	+++	--



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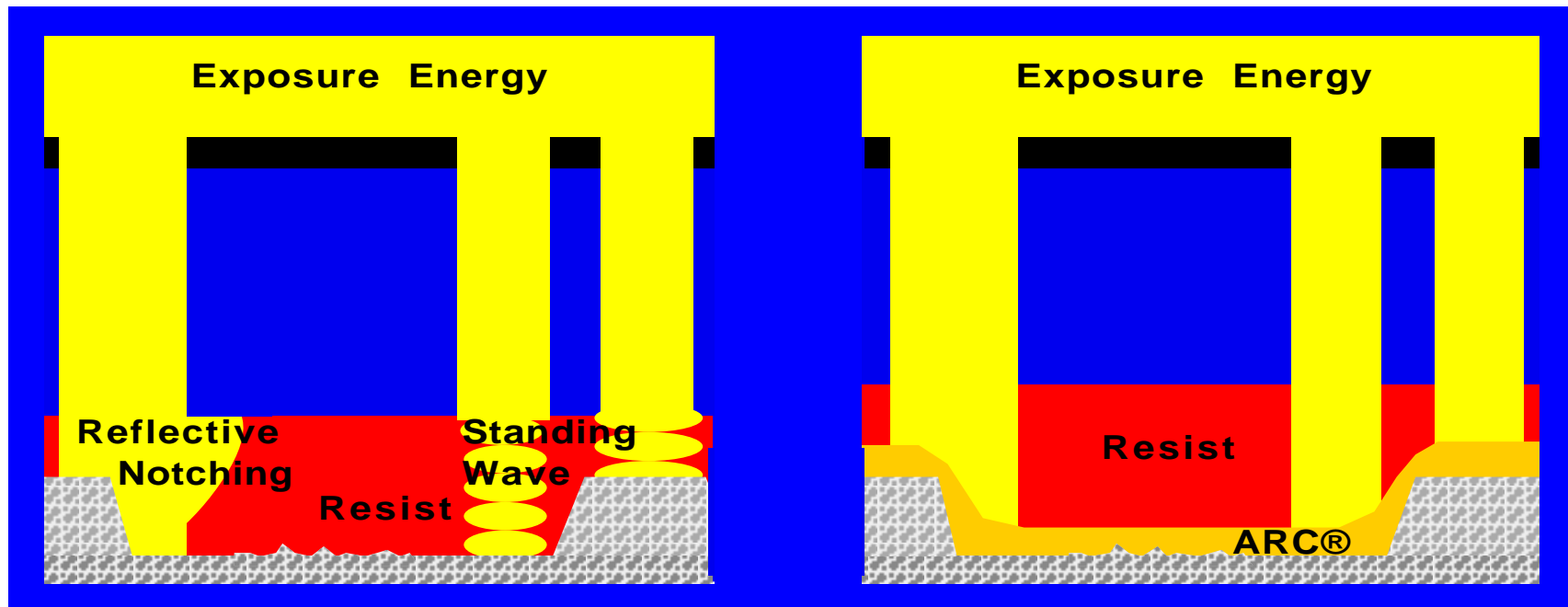
# Advantages of Anti-Reflective Coatings

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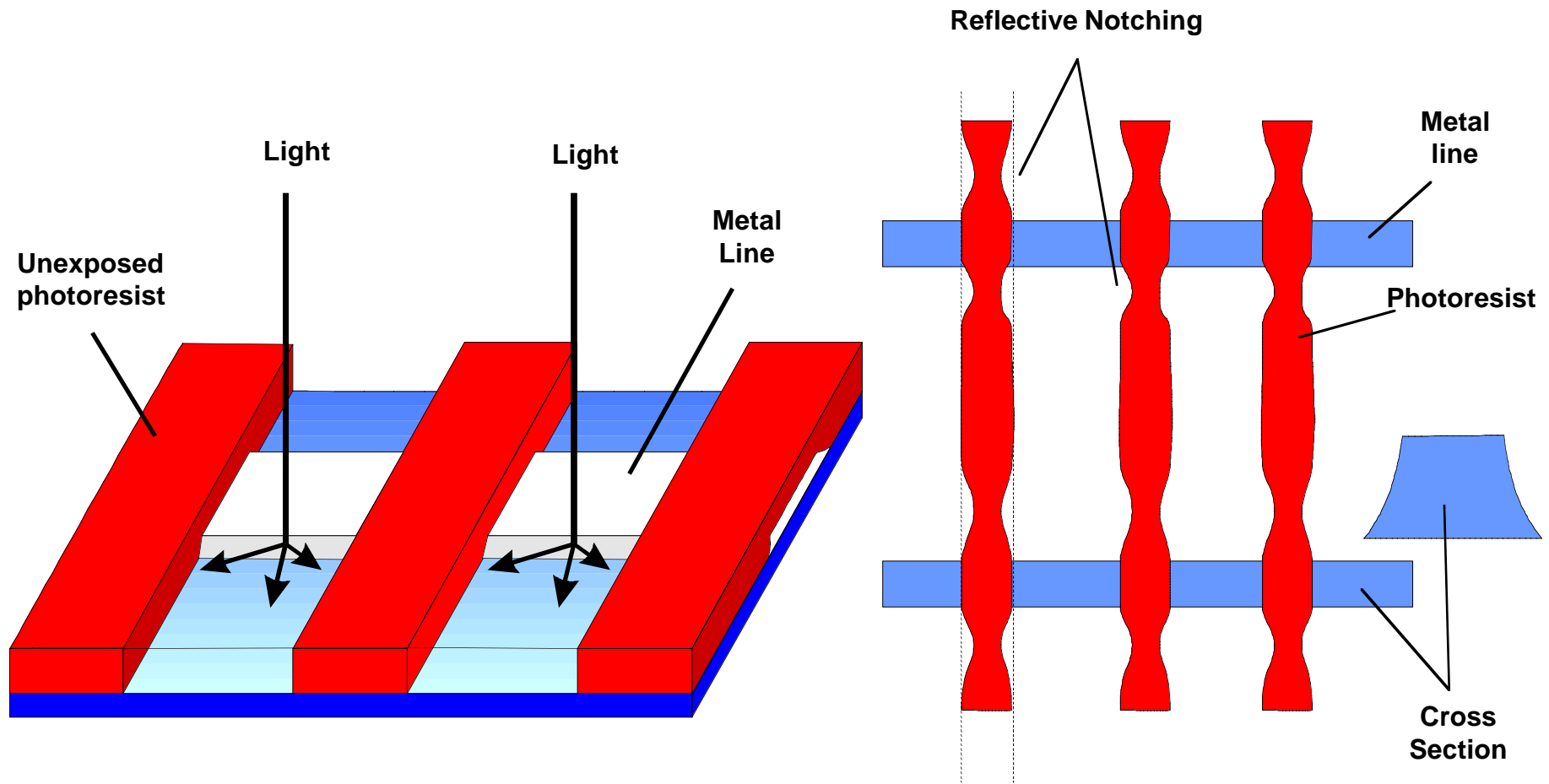
- Eliminates swing effect and standing waves in photoresist
- Solves topography related lithography problems
- Provides ultimate critical dimension (CD) control
- Expands process capabilities.

# Topography Related Lithography Problems

- Light reflecting off underlying substrate reduced or eliminated
  - Backscattering
  - Reflective notching
  - Standing Waves



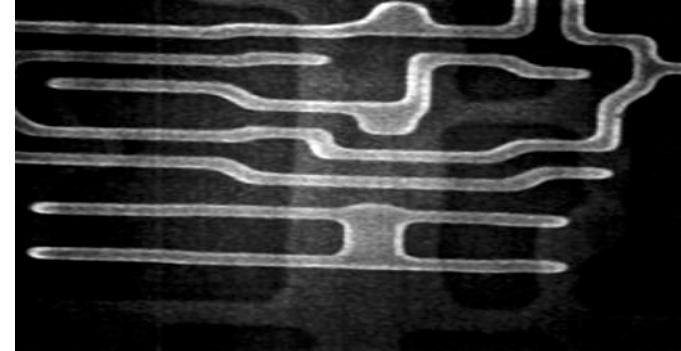
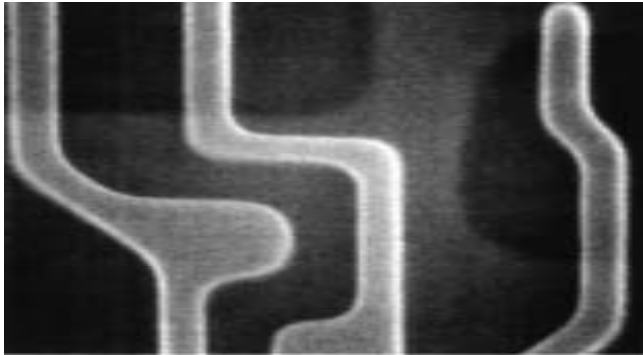
# Reflective Notching



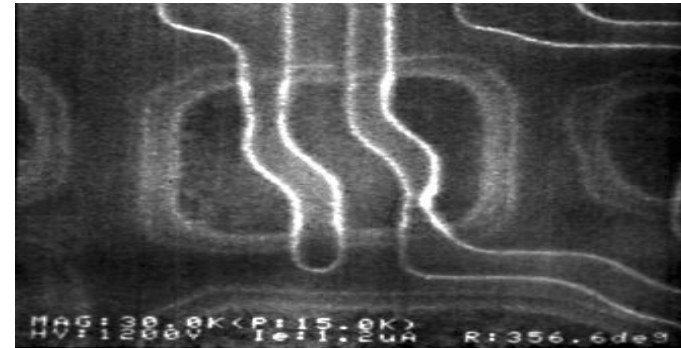
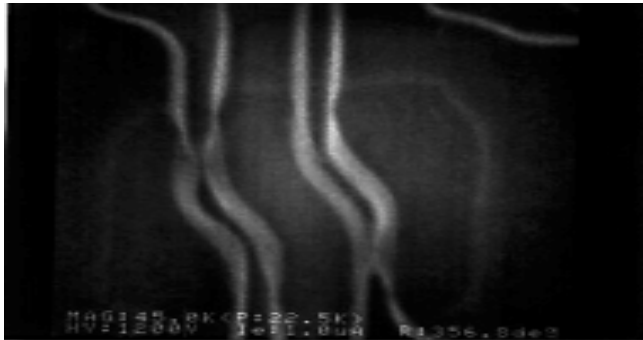


# Reflective Notching

0.4 $\mu\text{m}$  on 2500 $\text{\AA}$  steps using 1844 $\text{\AA}$  XHRi

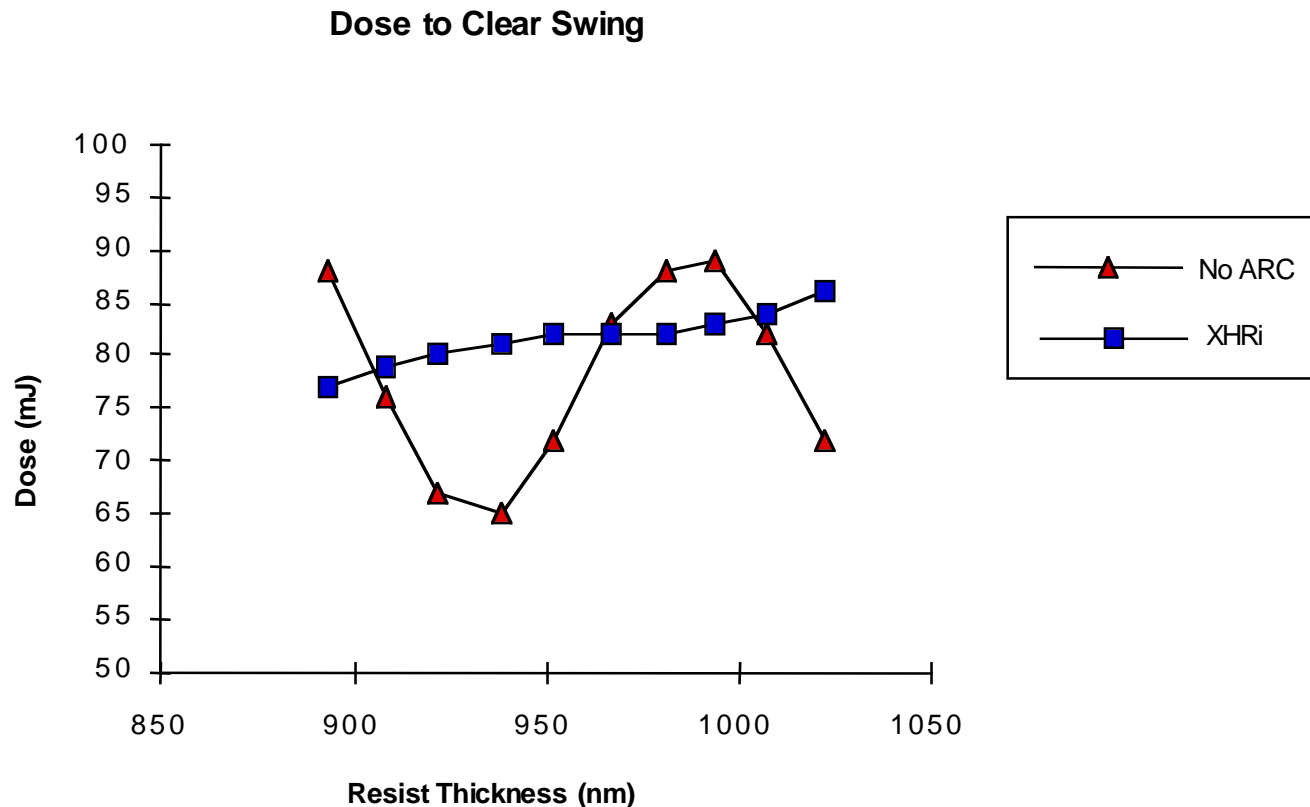


Competitor BARC

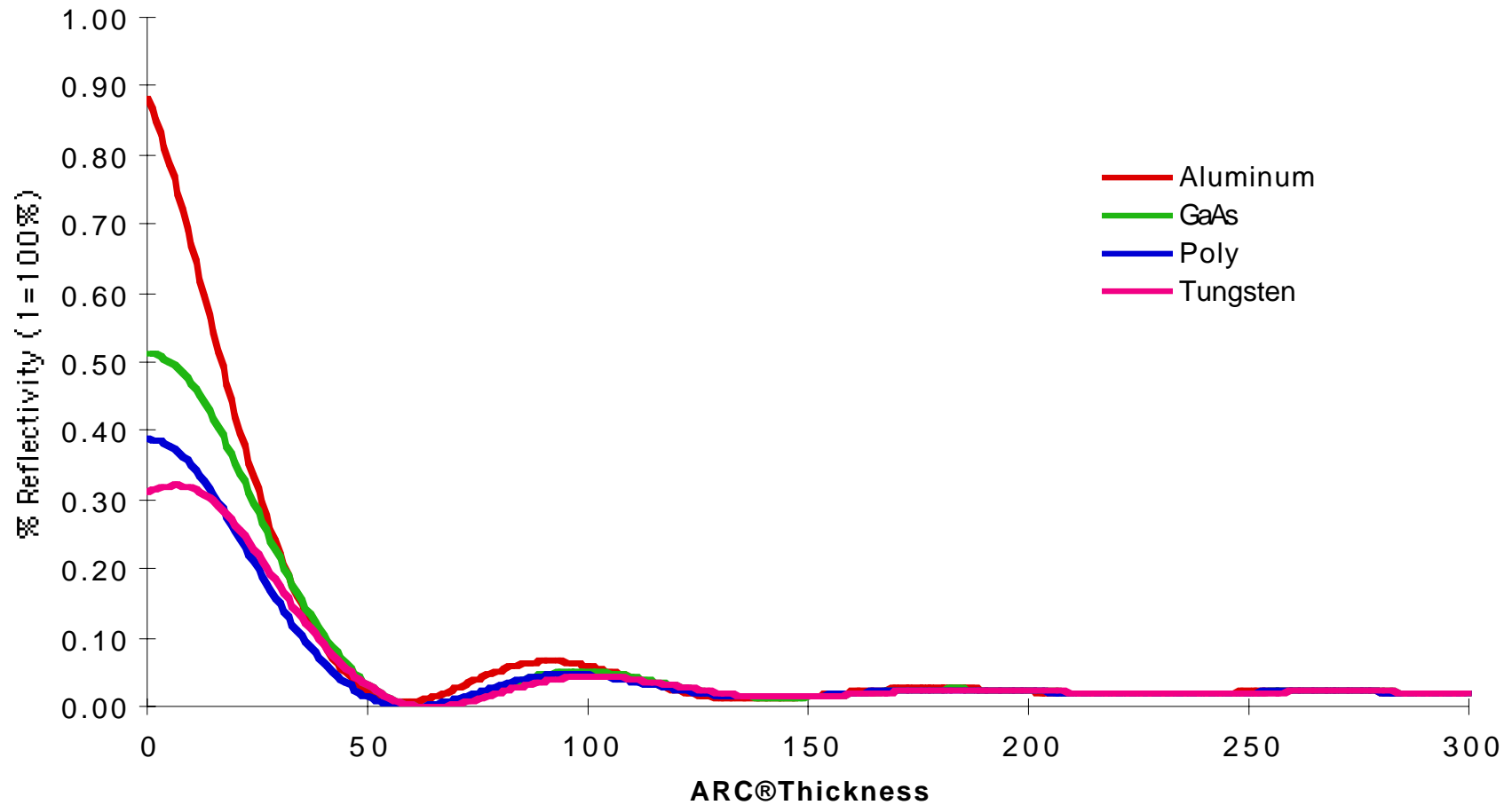


# Swing Effects

- Dose to clear swing curve defined as the amount of light required to completely expose photoresist
- Swing curves reduced with application of BARC



# BARC Reflectivity Curve



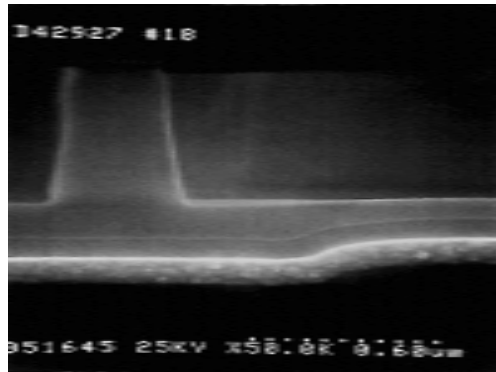
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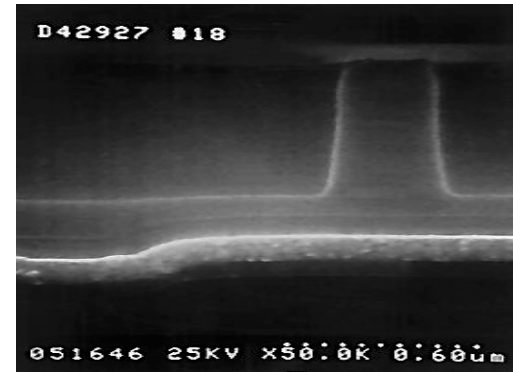
# Resist Profiles on Topography

0.4 $\mu\text{m}$  with 2500 $\text{\AA}$  Steps with 1844 $\text{\AA}$  ARC XHRi

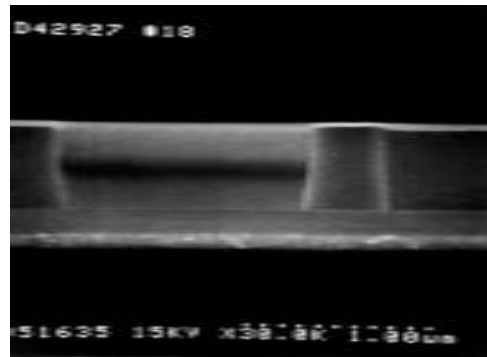
Low Area



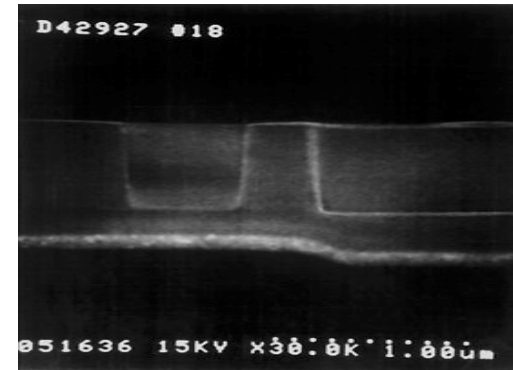
High Area



Flat Area



Transition



# Advantages of organic BARC

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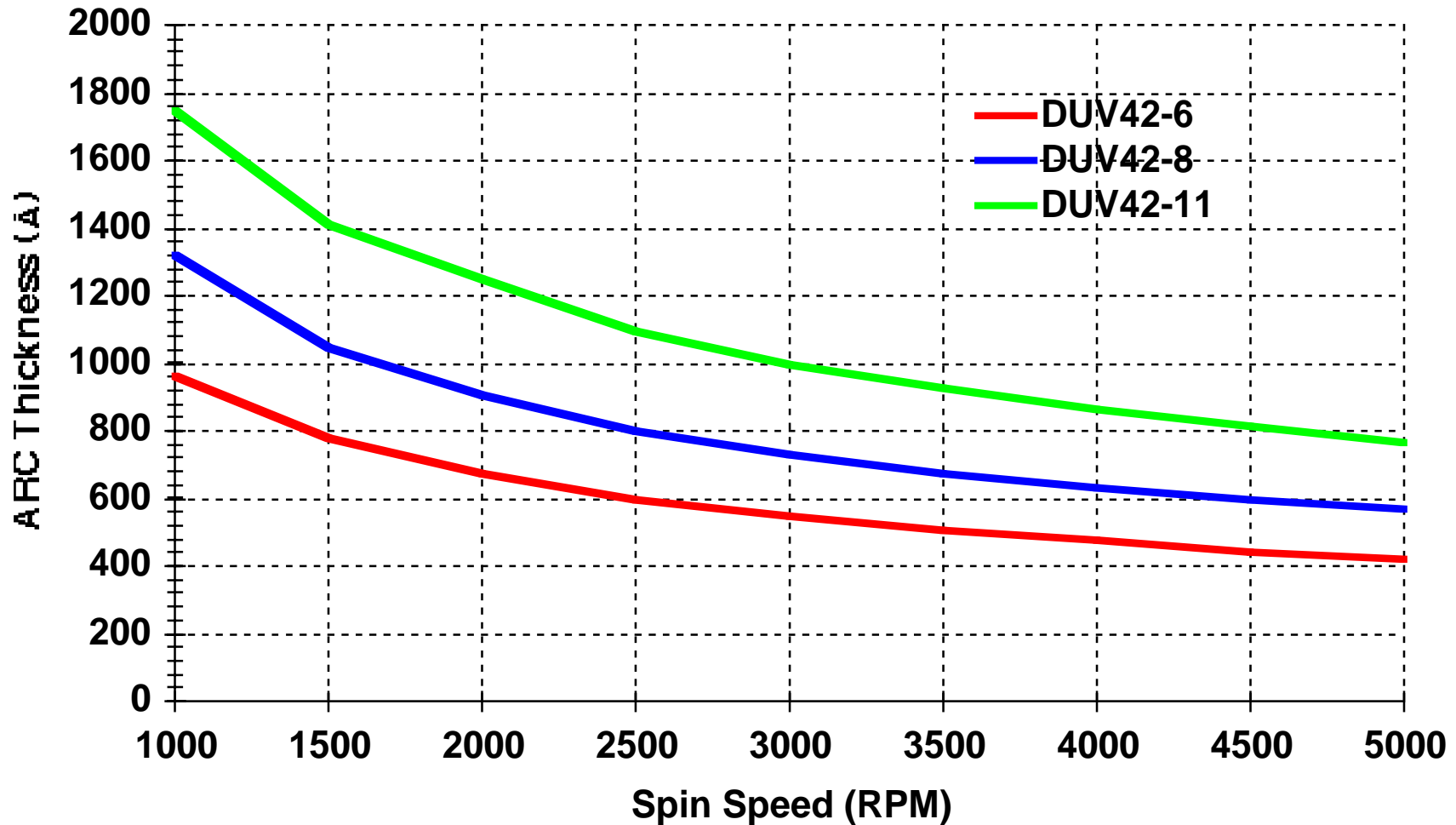
- Can apply with existing photoresist application systems
- Do not need expensive deposition chambers
- Prevents chemical interaction between photoresist and substrate
  - BARC acts as wall to nitrogen poisoning with chemically amplified photoresists
- Increases CD control
  - Eliminates reflective notching
  - Eliminates standing waves and scattered light
- Extends lithography process window
  - Increases stepper focus latitude
  - Maximizes photoresist exposure latitude
  - Increases usage life of stepper.



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# Example Spin Speed Curve



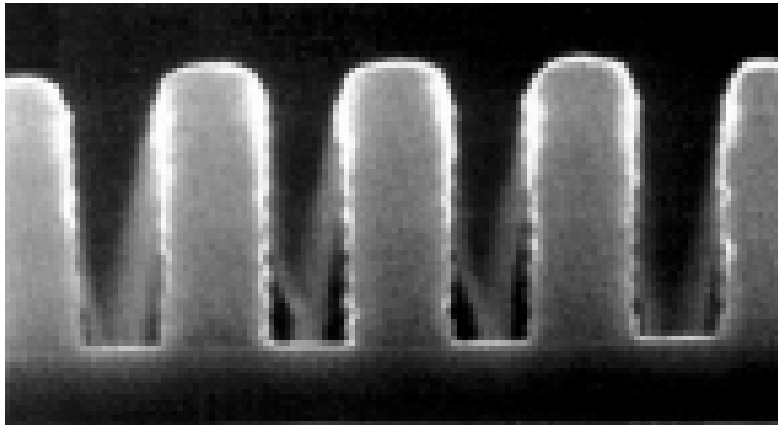
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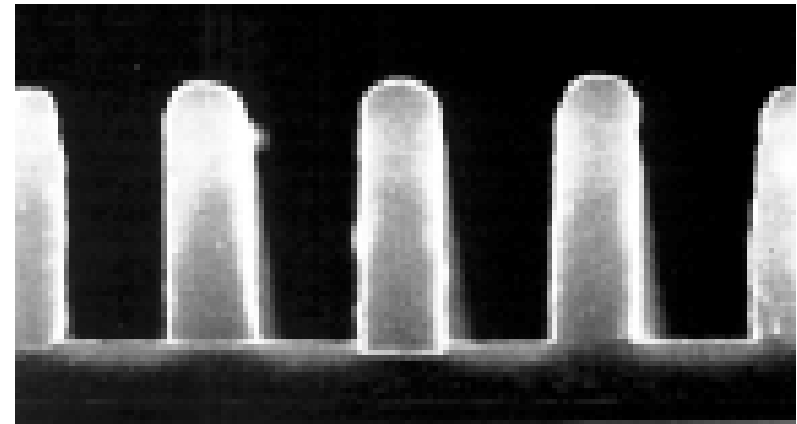
# Lines With or Without BARC

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PEK-103 0.20 $\mu$ m L/S



Resist on DUV42



# Guide to BSI BARC's

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- Exposure wavelength
  - G-line, I-line, DUV, 193nm
- Planar or conformal BARC
  - Worst case step height
  - CD tolerances needed
- Wet or dry processing
  - Depending on equipment availability, CD and wavelength
  - Wet process BARC develops away with resist
  - Dry process BARC requires a gas etcher
- Choose BARC based on resist chosen
  - DUV resists have two chemistries
    - ACETAL
    - ESCAP/TBOC

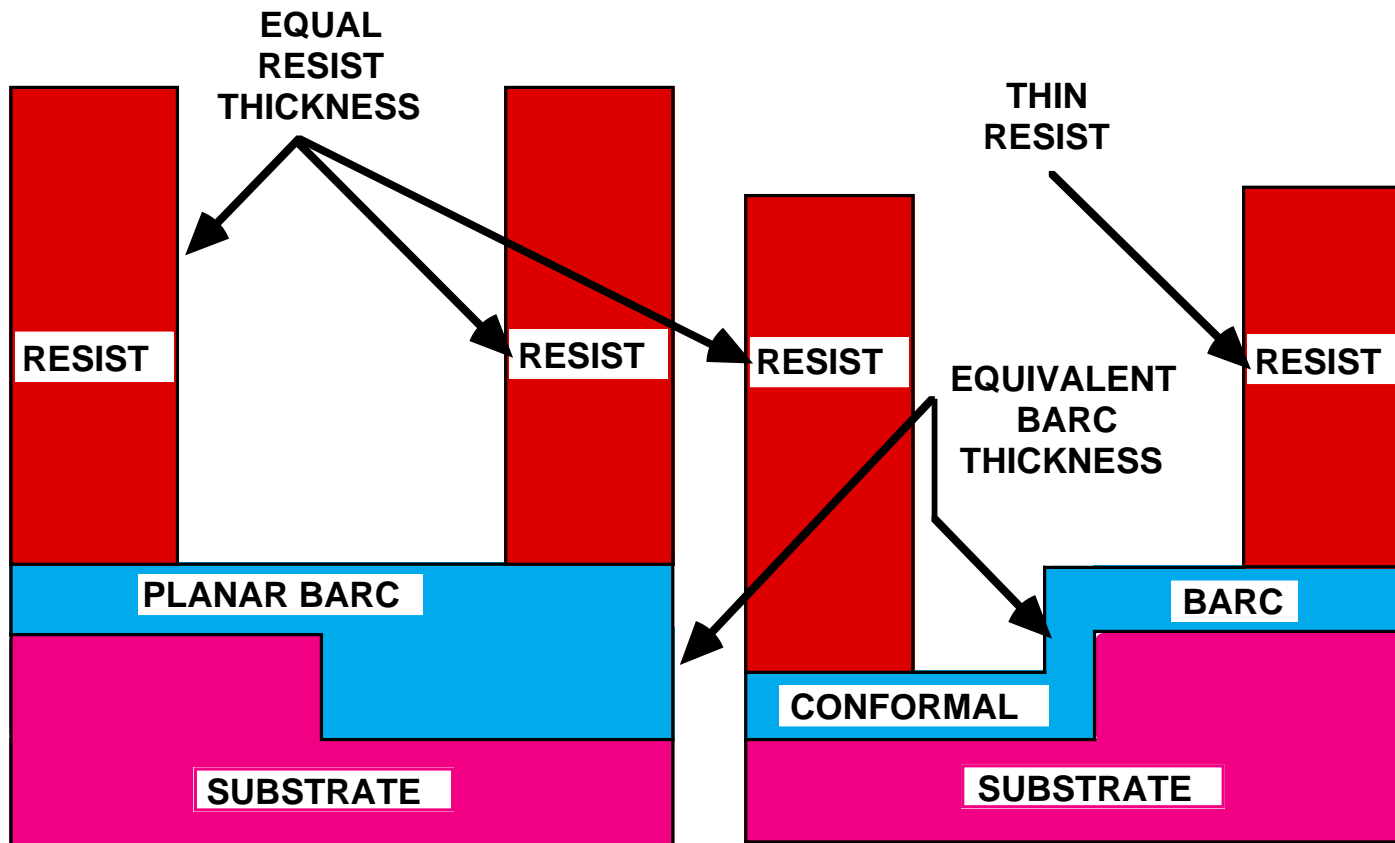


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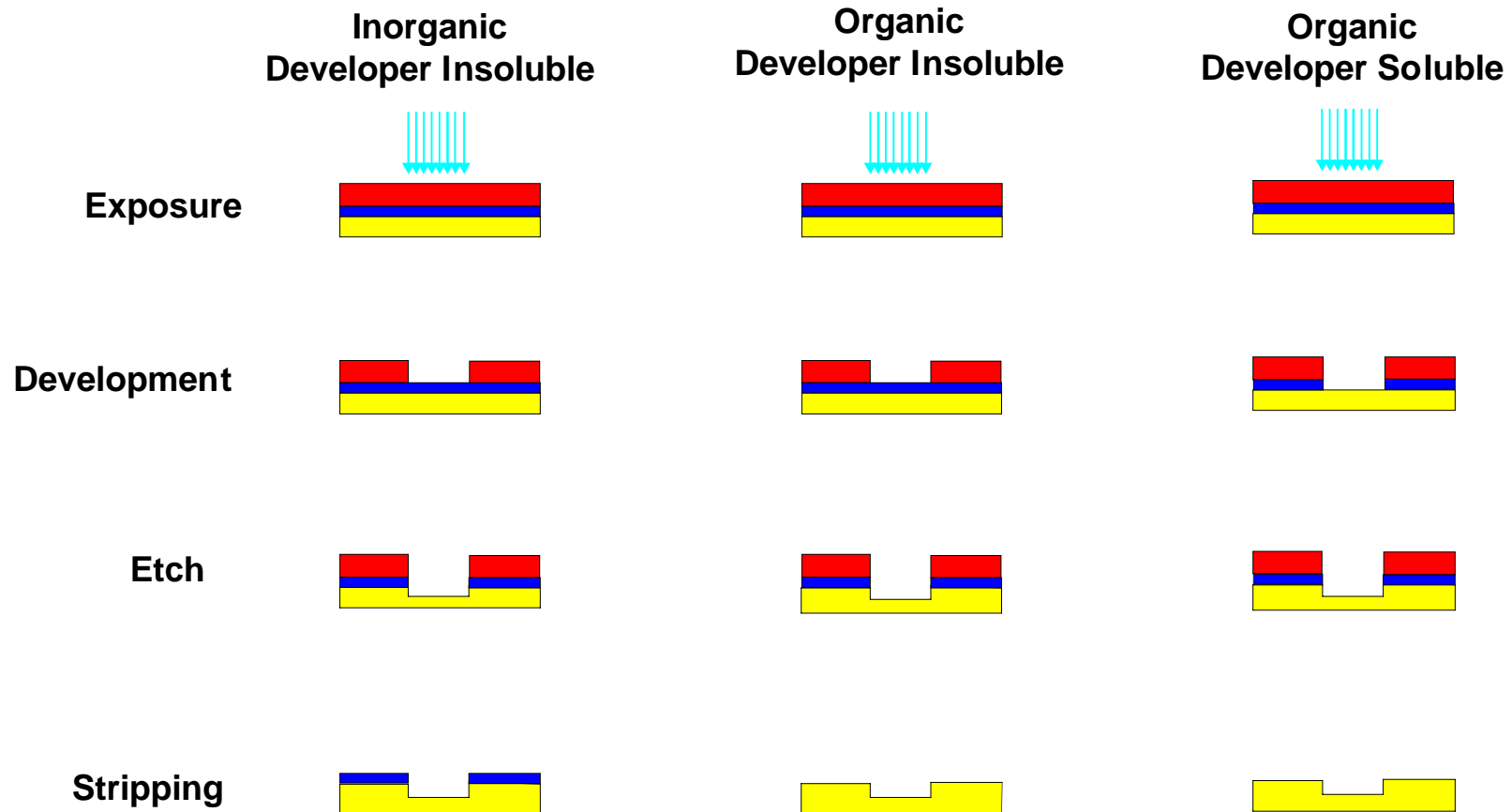
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# Planar vs Conformal BARC



# Wet or Dry Etch Processing



Substrate



Anti-reflective Bottom coat

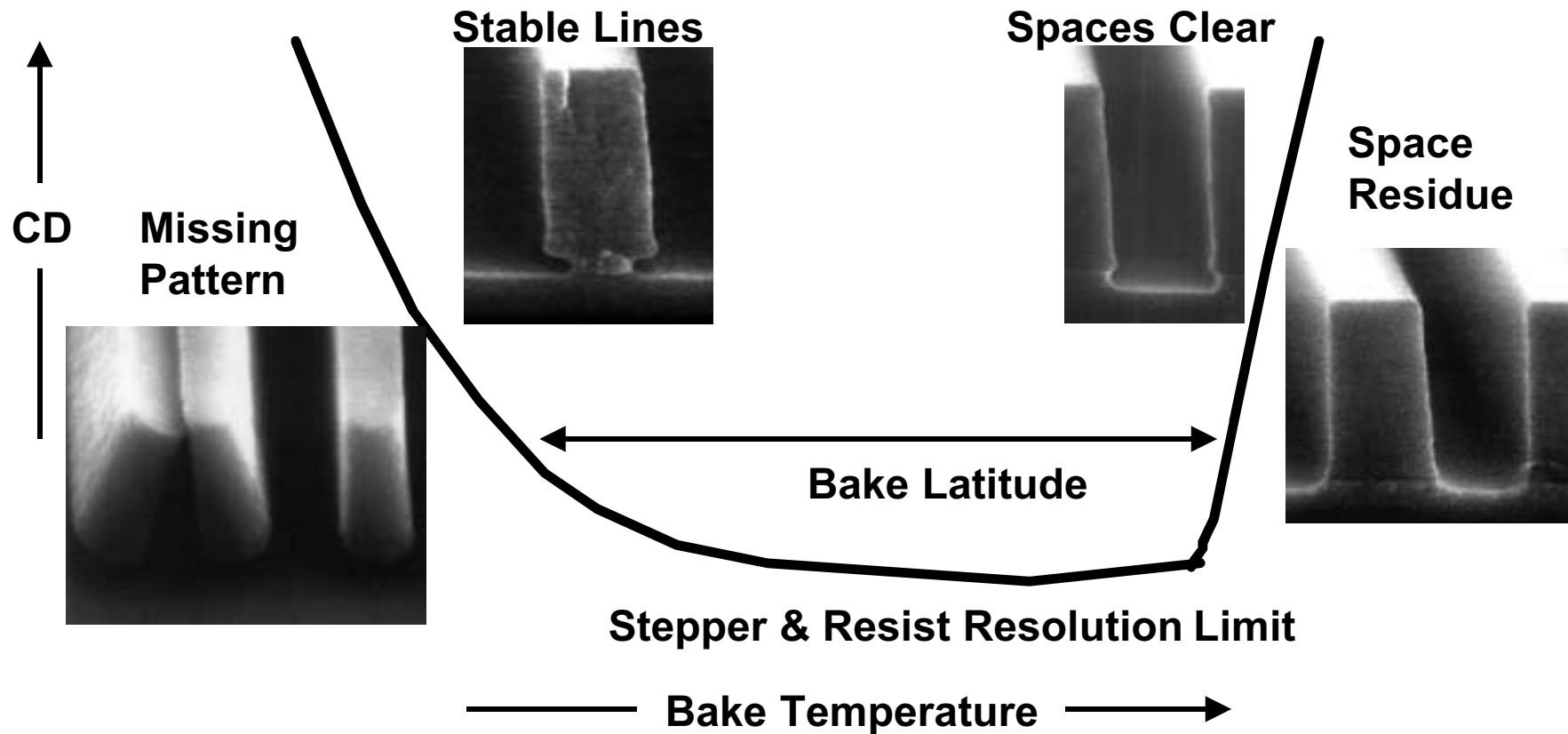


Photoresist

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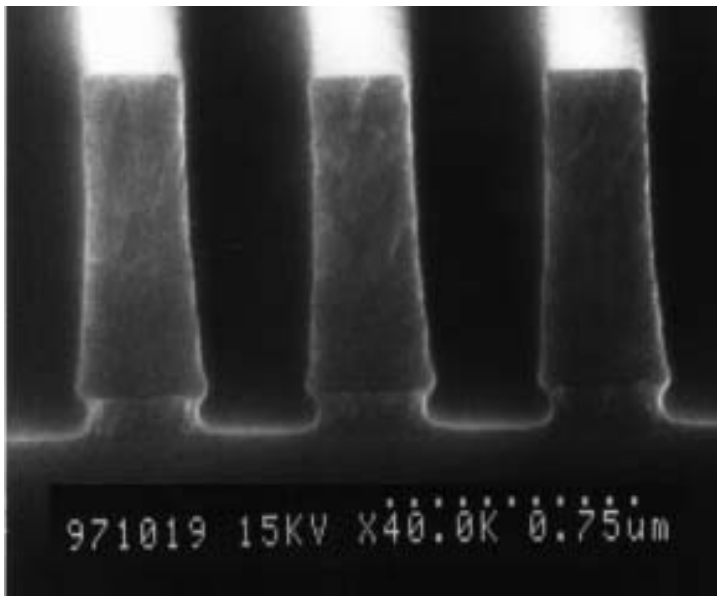
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# What is a Bake Window?

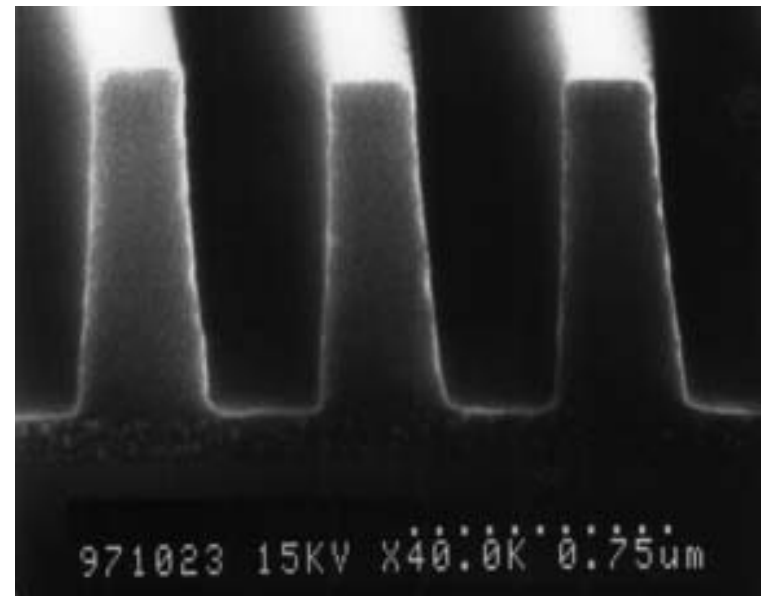


# Wet or Dry Etch Patterning

## 0.35 $\mu\text{m}$ Dense Lines



**177°C Bake**



**205°C Bake**

# BSI BARC Product Families

- **G-line (broadband material)**
  - Wet or dry process
    - XLT
    - XLX
- **I-line**
  - Wet or dry process
    - WiDE
  - Dry process only
    - XHRi
    - XHRiA
- **DUV**
  - Dry Process Only
  - ESCAP/TBOC compatible
    - DUV30 (planar)
    - DUV42 (conformal)
  - ACETAL compatible
    - DUV32 (planar)
    - DUV44 (conformal)

**Planar BARC gives superior photo performance**  
**Conformal BARC gives superior etch performance**

**Various viscosities available in each family**



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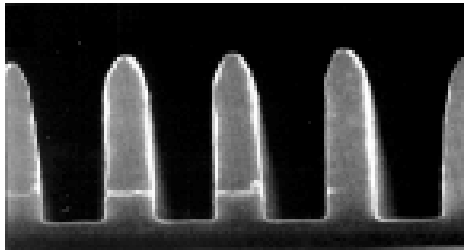
# Etch Capabilities

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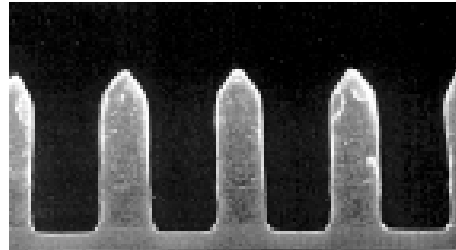
- Successfully dry etched in various chemistries
  - HBr
  - O<sub>2</sub>
  - Cl<sub>2</sub>, HCl
  - CF<sub>4</sub>, C<sub>2</sub>F<sub>2</sub>
  - N<sub>2</sub>
  - Carrier gases: He, Ar

# DUV42 Etch Performance

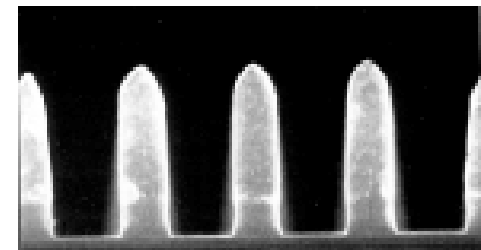
After He/O<sub>2</sub> etch.  
 $\Delta\text{CD} = 0.024\mu\text{m}$ .  
Selectivity = 1.04



After Cl<sub>2</sub>/O<sub>2</sub> etch.  
 $\Delta\text{CD} = 0.013\mu\text{m}$ .  
Selectivity = 1.48



After HBr/O<sub>2</sub> etch.  
 $\Delta\text{CD} = 0.026\mu\text{m}$ .  
Selectivity = 0.85



# Cleaning/Stripping Capability

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- BARC can be removed by common photoresist stripping processes
  - Oxidizing plasma or oxidizing solvent strip processes
    - Ozone Plasma Strip
    - O<sub>2</sub> Plasma
    - Piranha
    - RCA Clean